



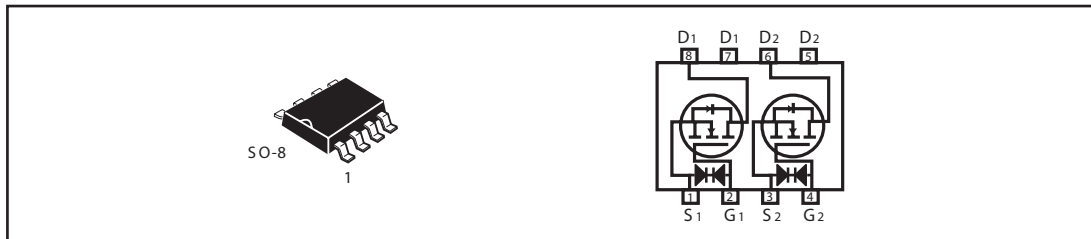
STM6968

Dual N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V _{DSS}	I _D	R _{DS(ON)} (mΩ) Max
60V	5A	60 @ V _{GS} = 10V 70 @ V _{GS} = 4.5V

FEATURES

- Super high dense cell design for low R_{DS(ON)}.
- Rugged and reliable.
- Surface Mount Package.
- ESD Protected.



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	60	V	
Gate-Source Voltage	V _{GS}	±20	V	
Drain Current-Continuous ^a @ T _a	I _D	25°C	5	A
		70°C	4.3	A
-Pulsed ^b	I _{DM}	25	A	
Drain-Source Diode Forward Current ^a	I _S	1.7	A	
Maximum Power Dissipation ^a	P _D	T _a =25°C	2	W
		T _a =70°C	1.44	
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C	

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient ^a	R _{θJA}	62.5	°C/W
--	------------------	------	------

STM6968

ELECTRICAL CHARACTERISTICS (T_A 25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D = 250µA	60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 48V, V _{GS} = 0V			1	µA
Gate-Body Leakage	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±10	µA
ON CHARACTERISTICS^b						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250µA	1.0	1.7	3	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} = 10V, I _D = 4.5A		49	60	m ohm
		V _{GS} = 4.5V, I _D = 3A		55	70	m ohm
On-State Drain Current	I _{D(ON)}	V _{DS} = 5V, V _{GS} = 10V	20			A
Forward Transconductance	g _{FS}	V _{DS} = 4.5V, I _D = 4.5A		13		S
DYNAMIC CHARACTERISTICS^c						
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz		685		pF
Output Capacitance	C _{OSS}			85		pF
Reverse Transfer Capacitance	C _{RSS}			50		pF
Gate resistance	R _g	V _{GS} = 0V, V _{DS} = 0V, f = 1.0MHz		2		ohm
SWITCHING CHARACTERISTICS^c						
Turn-On Delay Time	t _{D(ON)}	V _{DD} = 30V I _D = 4.5 A V _{GS} = 10V R _{GEN} = 6 ohm		11		ns
Rise Time	t _r			12		ns
Turn-Off Delay Time	t _{D(OFF)}			38		ns
Fall Time	t _f			8		ns
Total Gate Charge	Q _g	V _{DS} = 48V, I _D = 4.5A, V _{GS} = 10V		12.7		nC
		V _{DS} = 48V, I _D = 4.5A, V _{GS} = 4.5V		6.9		nC
Gate-Source Charge	Q _{gs}	V _{DS} = 48V, I _D = 4.5 A		1.8		nC
Gate-Drain Charge	Q _{gd}	V _{GS} = 10V		3.6		nC

STM6968

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS ^b						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_s = 1.7A$		0.8	1.2	V

Notes

- a. Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.
- b. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- c. Guaranteed by design, not subject to production testing.

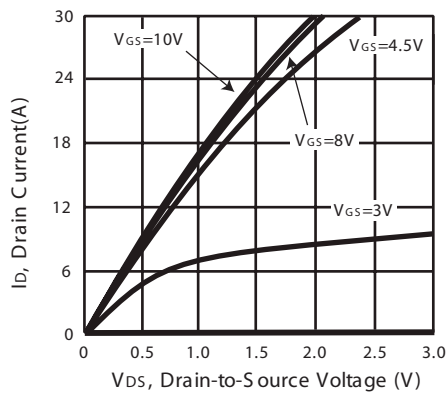


Figure 1. Output Characteristics

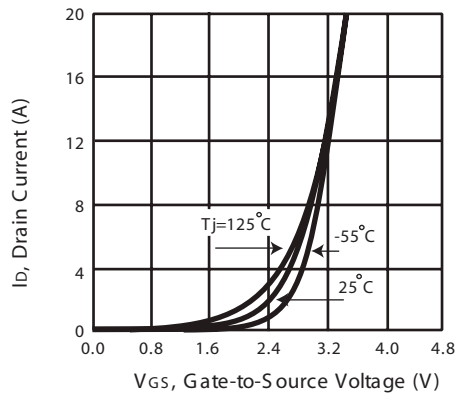


Figure 2. Transfer Characteristics

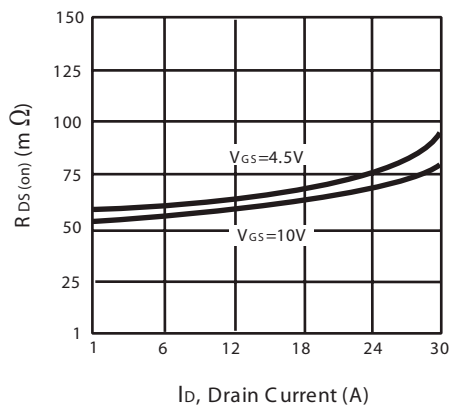


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

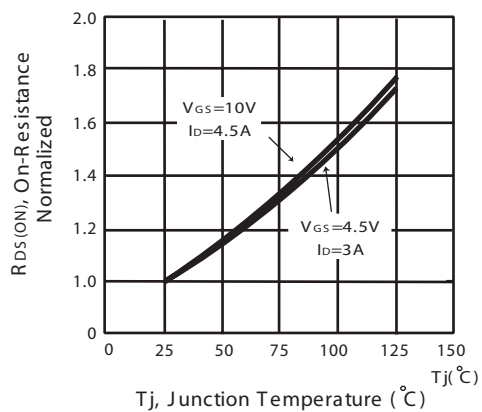


Figure 4. On-Resistance Variation with Drain Current and Temperature

STM6968

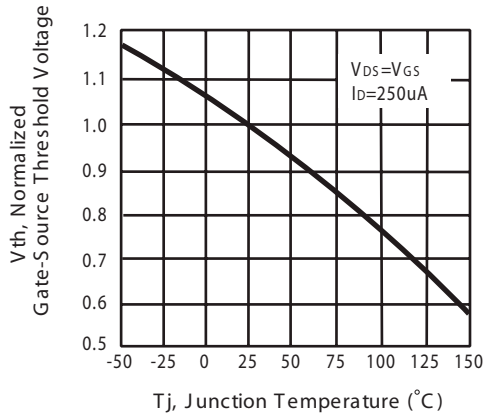


Figure 5. Gate Threshold Variation with Temperature

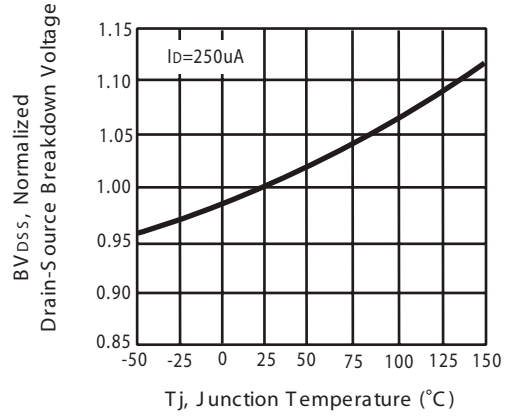


Figure 6. Breakdown Voltage Variation with Temperature

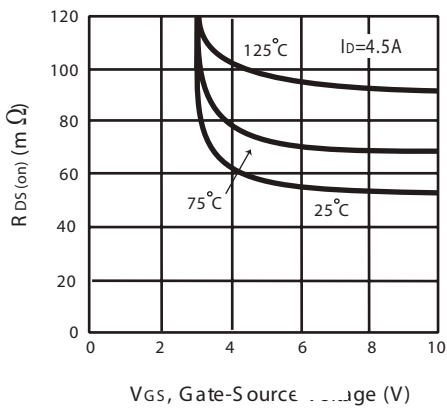


Figure 7. On-Resistance vs. Gate-Source Voltage

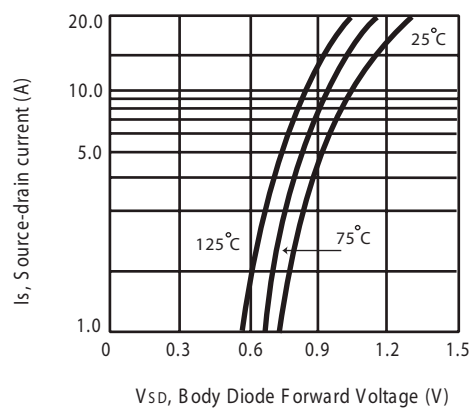


Figure 8. Body Diode Forward Voltage Variation with Source Current

STM6968

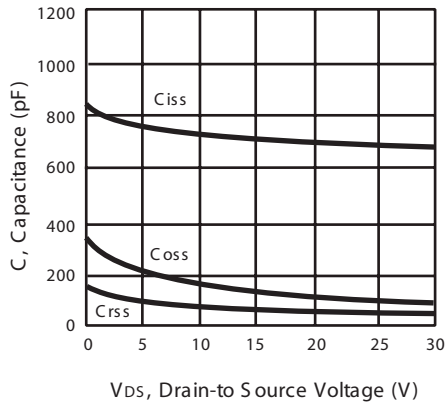


Figure 9. Capacitance

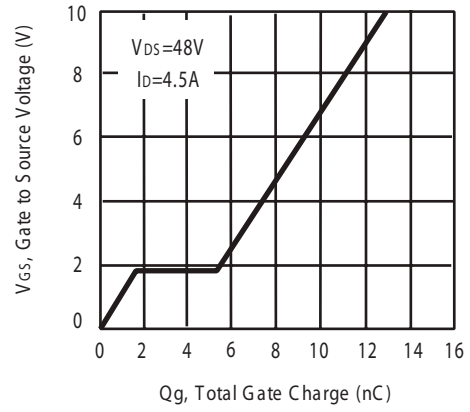


Figure 10. Gate Charge

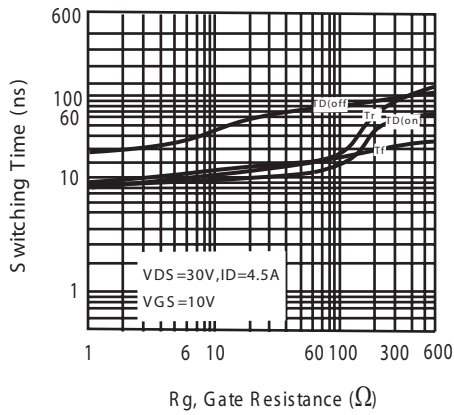


Figure 11. switching characteristics

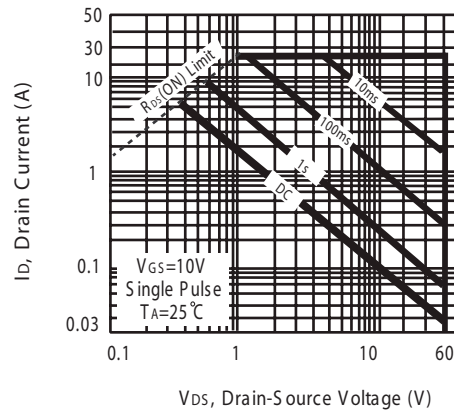
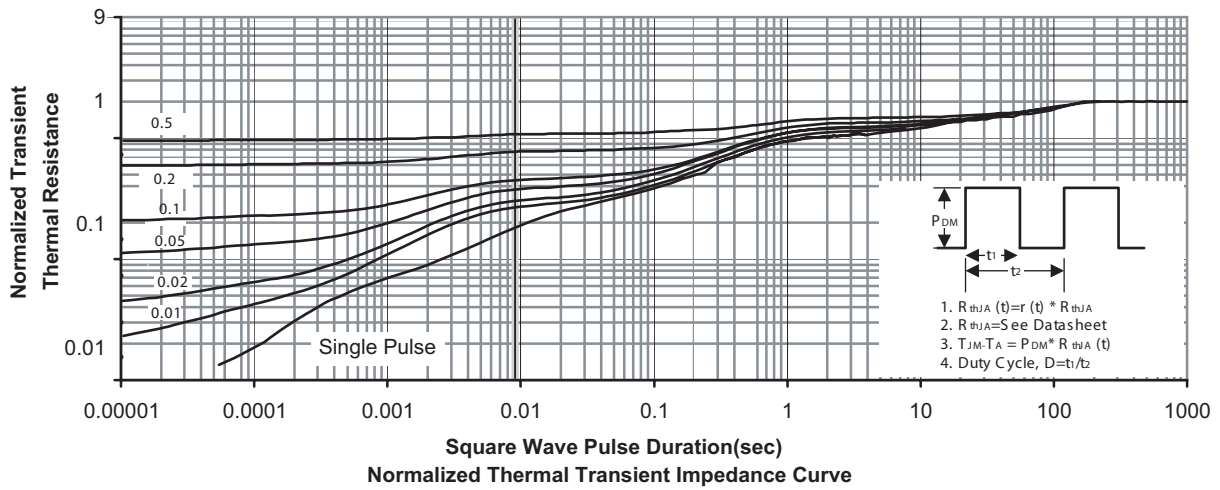


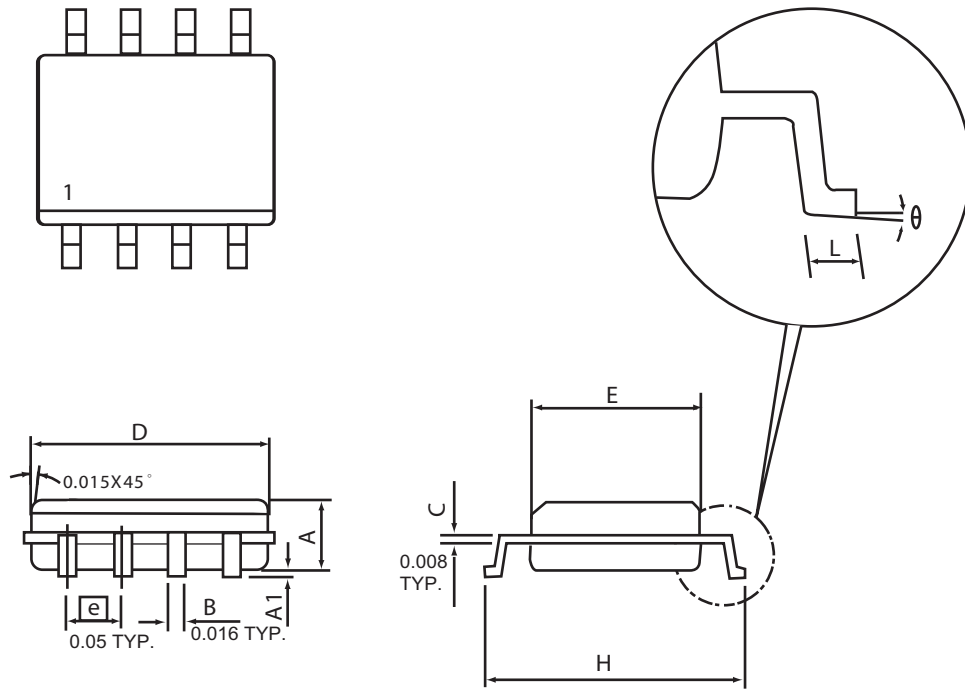
Figure 12. Maximum Safe Operating Area



STM6968

PACKAGE OUTLINE DIMENSIONS

SO-8

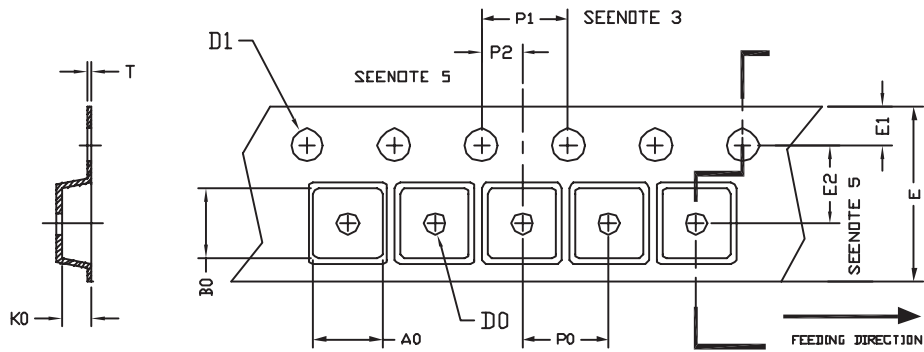


SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
D	4.80	4.98	0.189	0.196
E	3.81	3.99	0.150	0.157
H	5.79	6.20	0.228	0.244
L	0.41	1.27	0.016	0.050
θ	0°	8°	0°	8°

STM6968

SO-8 Tape and Reel Data

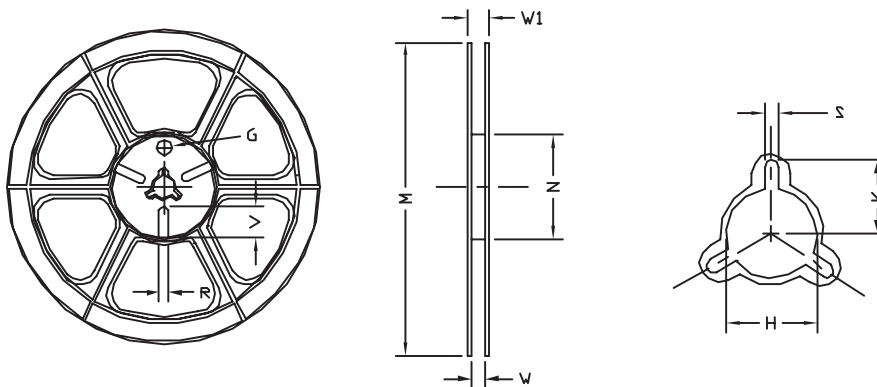
SO-8 Carrier Tape



unit: mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SOP 8N 150mil	6.40	5.20	2.10	$\phi 1.5$ (MIN)	$\phi 1.5$ + 0.1 - 0.0	12.0 ± 0.3	1.75	5.5 ± 0.05	8.0	4.0	2.0 ± 0.05	0.3 ± 0.05

SO-8 Reel



UNIT: mm

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
12 mm	$\phi 330$	330 ± 1	62 ± 1.5	12.4 + 0.2	16.8 - 0.4	$\phi 12.75$ + 0.15	---	2.0 ± 0.15	---	---	---